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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



BLM7G1822S-80AB; BLM7G1822S-80ABG

Rev. 3 — 1 September 2015

AMPLEON Product data sheet

Product profile 1.

1.1 General description

The BLM7G1822S-80AB(G) is a dual section, asymmetric, 2-stage power MMIC using Ampleon's state of the art GEN7 LDMOS technology. This multiband device is perfectly suited as small cell final stage in Doherty configuration, or as general purpose driver in the 1805 MHz to 2170 MHz frequency range. Available in gull wing or straight lead outline.

Table 1. Performance

Typical RF performance at T_{case} = 25 °C. Test signal: 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF; specified in a class-AB production circuit.

| Test signal | f | I _{Dq1} [1] | I _{Dq2} [1] | V _{DS} | P _{L(AV)} | G _p | η _D | ACPR _{5M} |
|-----------------------|--------|----------------------|----------------------|-----------------|--------------------|----------------|----------------|--------------------|
| | (MHz) | (mA) | (mA) | (V) | (W) | (dB) | (%) | (dBc) |
| single carrier W-CDMA | | | | | | | | |
| carrier section | 2167.5 | 40 | 120 | 28 | 4 | 30 | 24 | -39.5 |
| peaking section | 2167.5 | 80 | 240 | 28 | 8 | 28.3 | 24 | -36 |

[1] I_{Da1} represents driver stage; I_{Da2} represents final stage.

1.2 Features and benefits

- Designed for broadband operation (frequency 1805 MHz to 2170 MHz)
- High section-to-section isolation enabling multiple combinations
- High Doherty efficiency thanks to 2 : 1 asymmetry
- Integrated temperature compensated bias
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- On-chip matching for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

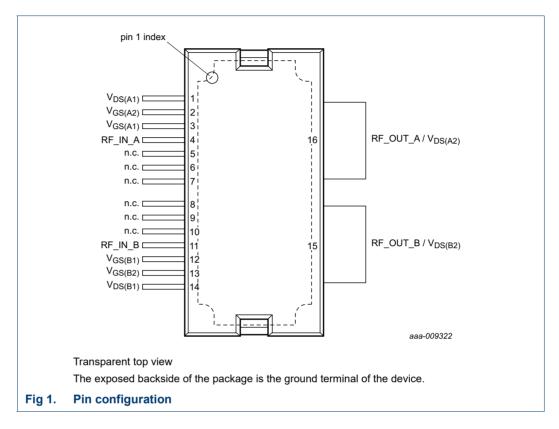
1.3 Applications

- RF power MMIC for W-CDMA base stations in the 1805 MHz to 2170 MHz frequency range. Possible circuit topologies are the following as also depicted in Section 8.1:
 - Asymmetric final stage in Doherty configuration
 - Asymmetric driver for high power Doherty amplifier

LDMOS 2-stage power MMIC

2. Pinning information

2.1 Pinning



2.2 Pin description

Table 2. **Pin description** Symbol Pin Description 1 drain-source voltage of carrier section, driver stage (A1) V_{DS(A1)} 2 gate-source voltage of carrier section, final stage (A2) V_{GS(A2)} 3 gate-source voltage of carrier section, driver stage (A1) V_{GS(A1)} RF_IN_A 4 RF input carrier section (A) 5 not connected n.c. 6 n.c. not connected 7 not connected n.c. 8 not connected n.c. 9 not connected n.c. 10 not connected n.c. RF input peaking section (B) RF_IN_B 11 12 gate-source voltage of peaking section, driver stage (B1) V_{GS(B1)} V_{GS(B2)} 13 gate-source voltage of peaking section, final stage (B2) 14 drain-source voltage of peaking section, driver stage (B1) V_{DS(B1)}

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Product data sheet

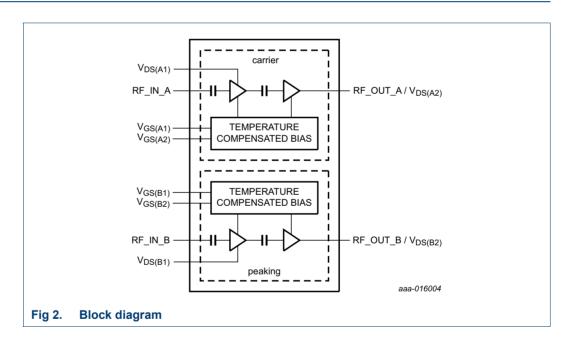
Symbol Pin Description RF_OUT_B/V_{DS(B2)} 15 RF output peaking section (B) / drain-source voltage of peaking section, final stage (B2) RF_OUT_A/V_{DS(A2)} 16 RF output carrier section (A) / drain-source voltage of carrier section, final stage (A2) GND flange RF ground

3. Ordering information

Table 3.Ordering information

| Type number | Package | ickage | | | | | | | |
|------------------|------------------|--|-----------|--|--|--|--|--|--|
| | Name Description | | | | | | | | |
| BLM7G1822S-80AB | HSOP16F | plastic, heatsink small outline package; 16 leads (flat) | SOT1211-2 | | | | | | |
| BLM7G1822S-80ABG | HSOP16 | plastic, heatsink small outline package; 16 leads | SOT1212-2 | | | | | | |

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|----------------------|------------|------|------|------|
| V _{DS} | drain-source voltage | | - | 65 | V |
| V _{GS} | gate-source voltage | | -0.5 | +13 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | <u>[1]</u> | - | 225 | °C |
| T _{case} | case temperature | | - | 150 | °C |

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

6. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Value | Unit | |
|----------------------|--|--|-------|------|-----|
| Carrier s | ection | | | | |
| R _{th(j-c)} | thermal resistance from junction to case | final stage; T _{case} = 90 °C; P _L = 1.26 W | [1] | 2.4 | K/W |
| | | driver stage; T _{case} = 90 °C; P _L = 1.26 W | [1] | 7.6 | K/W |
| Peaking | section | | | | |
| R _{th(j-c)} | thermal resistance from junction to case | final stage; T _{case} = 90 °C; P _L = 2.52 W | [1] | 1.5 | K/W |
| | | driver stage; T _{case} = 90 °C; P _L = 2.52 W | [1] | 5.5 | K/W |

[1] When operated with a CW signal.

7. Characteristics

Table 6. DC characteristics

T_{case} = 25 °C; per section unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------------|--|--|-----|-----|------|------|------|
| Carrier s | ection | | | | | | |
| Final stag | ge | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 0.302 mA | (| 65 | - | - | V |
| V _{GSq} | gate-source quiescent voltage | V _{DS} = 28 V; I _D = 120 mA | | 1.6 | 2 | 2.45 | V |
| | | V _{DS} = 28 V; I _D = 120 mA | [1] | 1.9 | 2.6 | 3.3 | V |
| $\Delta I_{Dq} / \Delta T$ | quiescent drain current variation with temperature | T _{case} = –40 °C to +85 °C | [1] | - | 1.5 | - | % |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | | - | - | 1.4 | μA |
| I _{DSX} | drain cut-off current | V _{GS} = 5.55 V; V _{DS} = 10 V | | - | 5.4 | - | А |
| I _{GSS} | gate leakage current | V _{GS} = 1.0 V; V _{DS} = 0 V | | - | - | 140 | nA |
| Driver sta | age | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 0.058 mA | (| 65 | - | - | V |
| V _{GSq} | gate-source quiescent voltage | V _{DS} = 28 V; I _D = 40 mA | | 1.7 | 2.1 | 2.55 | V |
| | | V _{DS} = 28 V; I _D = 40 mA | [2] | 1.9 | 2.6 | 3.2 | V |
| $\Delta I_{Dq} / \Delta T$ | quiescent drain current variation with temperature | T _{case} = -40 °C to +85 °C | [2] | - | 1.5 | - | % |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | | - | - | 1.4 | μA |
| I _{DSX} | drain cut-off current | V _{GS} = 5.55 V; V _{DS} = 10 V | | - | 1.05 | - | А |
| I _{GSS} | gate leakage current | V _{GS} = 1.0 V; V _{DS} = 0 V | | - | - | 140 | nA |
| Peaking | section | | | | | | |
| Final stag | ge | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 0.604 mA | (| 65 | - | - | V |
| V _{GSq} | gate-source quiescent voltage | V _{DS} = 28 V; I _D = 240 mA | | 1.6 | 2.15 | 2.6 | V |
| | | V _{DS} = 28 V; I _D = 240 mA | [3] | 2 | 3 | 3.8 | V |
| $\Delta I_{Dq} / \Delta T$ | quiescent drain current variation with temperature | T _{case} = -40 °C to +85 °C | [3] | - | 2 | - | % |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | | - | - | 1.4 | μA |
| I _{DSX} | drain cut-off current | V _{GS} = 5.55 V; V _{DS} = 10 V | | - | 11 | - | А |
| I _{GSS} | gate leakage current | V _{GS} = 1.0 V; V _{DS} = 0 V | | - | - | 140 | nA |

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LDMOS 2-stage power MMIC

Table 6. DC characteristics ... continued

 $T_{case} = 25 \ ^{\circ}C$; per section unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------------|--|--|-------------|------|------|------|
| Driver sta | ge | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 0.116 mA | 65 | - | - | V |
| V _{GSq} | gate-source quiescent voltage | V _{DS} = 28 V; I _D = 80 mA | 1.7 | 2.15 | 2.55 | V |
| | | V _{DS} = 28 V; I _D = 80 mA | <u>4]</u> 2 | 2.7 | 3.3 | V |
| $\Delta I_{Dq} / \Delta T$ | quiescent drain current variation with temperature | $T_{case} = -40 \text{ °C to } +85 \text{ °C}$ | <u>4]</u> | 2 | - | % |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | - | - | 1.4 | μA |
| I _{DSX} | drain cut-off current | V _{GS} = 5.55 V; V _{DS} = 10 V | - | 1.9 | - | А |
| I _{GSS} | gate leakage current | V _{GS} = 1.0 V; V _{DS} = 0 V | - | - | 140 | nA |

[1] In production circuit with 825 Ω gate feed resistor.

[2] In production circuit with 850 Ω gate feed resistor.

[3] In production circuit with 1205 Ω gate feed resistor.

[4] In production circuit with 460 Ω gate feed resistor.

Table 7.RF Characteristics

Typical RF performance at f = 2167.5 MHz; $T_{case} = 25 \text{ °C}$; $V_{DS} = 28 \text{ V}$; $I_{Dq1} = 40 \text{ mA}$ (carrier section, driver stage); $I_{Dq2} = 120 \text{ mA}$ (carrier section, final stage); $P_{L(AV)} = 4 \text{ W}$ (carrier section); $I_{Dq1} = 80 \text{ mA}$ (peaking section, driver stage); $I_{Dq2} = 240 \text{ mA}$ (peaking section, final stage); $P_{L(AV)} = 8 \text{ W}$ (peaking section) unless otherwise specified, measured in an Ampleon straight lead production circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------------|--------------------------------------|------------------------------|------|-------|-------|------|
| Carrier se | ction | I | I | | | |
| Test signa | l: single carrier W-CDMA [1] | | | | | |
| Gp | power gain | | 29.5 | 31 | 32.5 | dB |
| η _D | drain efficiency | | 21 | 24 | - | % |
| RL _{in} | input return loss | | - | -13.5 | -10 | dB |
| ACPR _{5M} | adjacent channel power ratio (5 MHz) | | - | -39.5 | -36.5 | dBc |
| PARO | output peak-to-average ratio | | 7 | 7.8 | - | dB |
| Peaking s | ection | | | | - | _ |
| Test signa | I: single carrier W-CDMA [1] | | | | | |
| G _p | power gain | | 26.8 | 28.3 | 29.8 | dB |
| η _D | drain efficiency | | 20 | 24 | - | % |
| RL _{in} | input return loss | | - | -20 | -10 | dB |
| ACPR _{5M} | adjacent channel power ratio (5 MHz) | | - | -36 | -31 | dBc |
| PARO | output peak-to-average ratio | | 5.2 | 7 | - | dB |
| Test signa | : CW [2] | | | | - | _ |
| $\Delta \phi_{s21}$ | phase response difference | normalized; between sections | -15 | - | +15 | deg |
| $\Delta \mathbf{s}_{21} ^2$ | insertion power gain difference | normalized; between sections | -0.6 | - | +0.6 | dB |

[1] 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF.

[2] f = 2170 MHz.

8. Application information

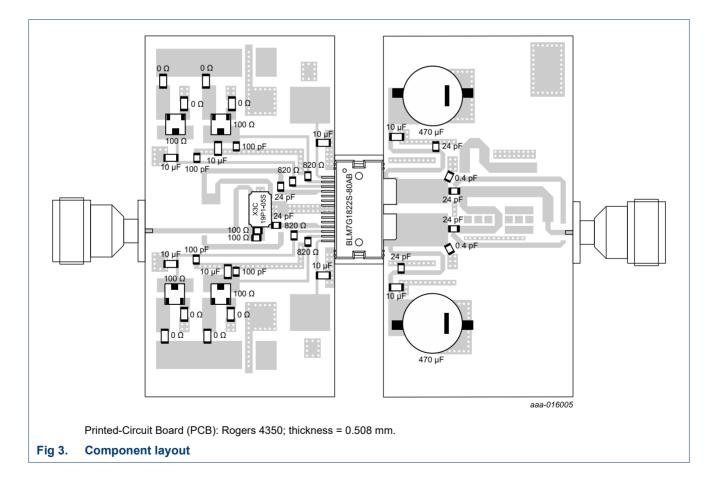
Table 8. Doherty typical performance

Test signal: 1-tone CW; RF performance at $T_{case} = 25 \ ^{\circ}C$; $V_{DS} = 28 \ V$; $I_{Dq1} = 40 \ mA$ (carrier section, driver stage); $I_{Dq2} = 90 \ mA$ (carrier section, final stage); $I_{Dq1} = 20 \ mA$ (peaking section, driver stage);

 $V_{GS} = 0.9 V$ (peaking section, final stage); unless otherwise specified, measured in an Ampleon, f = 1805 MHz to 1880 MHz, Doherty application circuit (see Figure 3 and Figure 4).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------------|--|-----|------|-----|------|
| P _{L(3dB)} | output power at 3 dB gain compression | f = 1842.5 MHz; 1-tone pulsed CW (10 % duty cycle) | - | 89 | - | W |
| η _D | drain efficiency | at P _{L(3dB)} ; f = 1842.5 MHz; 1-tone pulsed CW (10 % duty cycle) | - | 52.5 | - | % |
| G _p | power gain | P _{L(AV)} = 14.12 W; f = 1842.5 MHz | - | 26.3 | - | dB |
| B _{video} | video bandwidth | P _{L(AV)} = 6.3 W; f = 1842.5 MHz; 2-tone CW | - | 70 | - | MHz |
| G _{flat} | gain flatness | P _{L(AV)} = 14.12 W | - | 0.5 | - | dB |
| К | Rollett stability factor | $T_{case} = -40 \text{ °C}; f = 0.1 \text{ GHz to 3 GHz}$ [1] | | > 1 | - | |

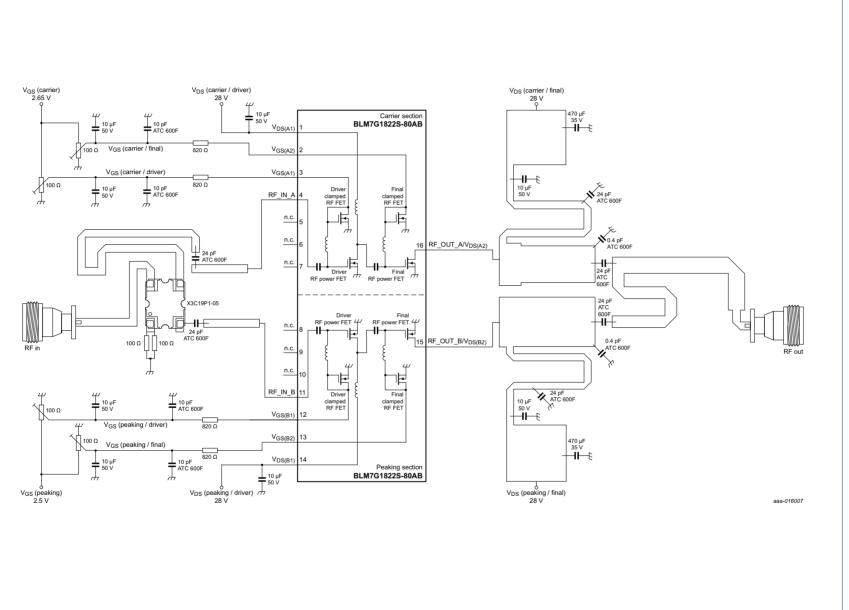
[1] For carrier and peaking sections (S-parameters measured with load-pull jig).



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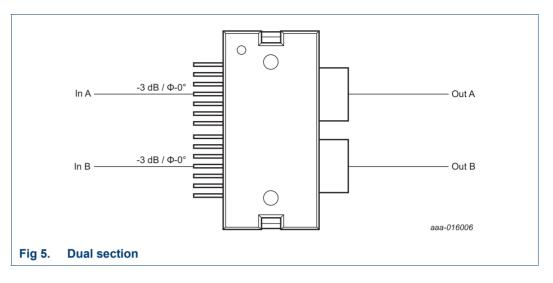
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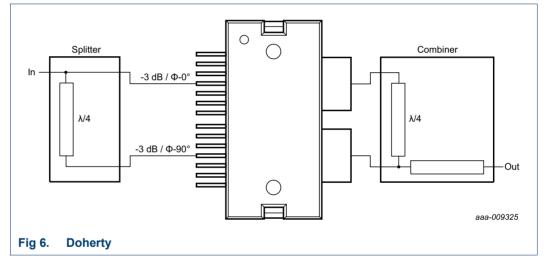
BLM7G1822S-80AB(G)

LDMOS 2-stage power MMIC

LDMOS 2-stage power MMIC

8.1 Possible circuit topologies





8.2 Ruggedness in class-AB operation

The BLM7G1822S-80AB and BLM7G1822S-80ABG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: f = 2140 MHz; V_{DS} = 32 V; I_{Dq1} = 40 mA (carrier section, driver stage); I_{Dq2} = 120 mA (carrier section, final stage); I_{Dq1} = 80 mA (peaking section, driver stage); I_{Dq2} = 180 mA (peaking section, final stage); P_i = 16 dBm (carrier section); P_i = 22 dBm (peaking section). P_i is measured at CW and corresponding to $P_{L(3dB)}$ under Z_S = 50 Ω load.

8.3 Impedance information

Table 9. Typical impedance

Measured load-pull data at 3 dB gain compression point; test signal: pulsed CW; $T_{case} = 25 \ C$; $V_{DS} = 28 \ V$; $t_p = 100 \ \mu s$; $\delta = 10 \ \%$; $Z_S = 50 \ \Omega$; $I_{Dq1} = 40 \ mA$ (carrier section, driver stage); $I_{Dq2} = 110 \ mA$ (carrier section, final stage); $I_{Dq1} = 80 \ mA$ (peaking section, driver stage); $I_{Dq2} = 200 \ mA$ (peaking section, final stage). Typical values unless otherwise specified.

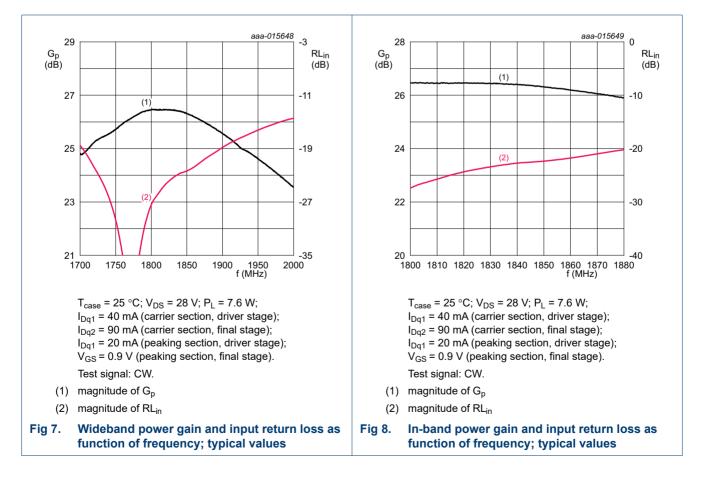
| | tuned for m | aximum o | utput p | ower | | tuned for maximum power added efficiency | | | | | |
|---------|-------------|---------------------|---------|------------------|---------------------|--|---------------------|------|------------------|---------------------|--|
| f | ZL | G _{p(max)} | PL | η _{add} | AM-PM conversion | ZL | G _{p(max)} | PL | η _{add} | AM-PM conversion | |
| (MHz) | (Ω) | (dB) | (W) | (%) | (deg) | (Ω) | (dB) | (W) | (%) | (deg) | |
| Carrier | section | | 1 | | I | | | 1 | | | |
| BLM7G | 1822S-80AB | | | | | | | | | | |
| 1805 | 7.7 – j10.6 | 32.2 | 45.8 | 51 | 0.3 | 16.7 – j4.2 | 33.5 | 43.9 | 58.8 | -4.9 | |
| 1842.5 | 7.8 – j10.6 | 32.3 | 45.8 | 51.8 | 0.9 | 16.2 – j5.6 | 33.4 | 44 | 58.5 | -3 | |
| 1880 | 7.7 – j10.6 | 32.3 | 45.8 | 52.1 | 1.4 | 12.2 – j4.6 | 33.4 | 44.5 | 58.4 | -2.8 | |
| 1930 | 6.7 – j10.8 | 32 | 45.7 | 48.8 | 0.3 | 11.6 – j3.4 | 33.5 | 44.1 | 57.7 | -4.3 | |
| 1960 | 7.8 – j10.6 | 32.6 | 45.7 | 51.4 | 1.6 | 9.9 – j4.4 | 33.6 | 44.6 | 57.6 | -2.3 | |
| 1990 | 6.3 – j9.5 | 32.5 | 45.7 | 49.1 | 0.5 | 8.6 – j4.3 | 33.6 | 44.6 | 57 | -3.1 | |
| 2110 | 6.3 – j9.5 | 33 | 45.8 | 51.4 | -4 | 7.3 – j4.8 | 33.8 | 44.6 | 56.4 | -4.4 | |
| 2140 | 6.3 – j9.5 | 33 | 45.7 | 51.8 | -5.9 | 7.3 – j4.8 | 33.8 | 44.5 | 56.2 | -5.4 | |
| 2170 | 6.8 – j10.8 | 32.8 | 45.6 | 50.1 | -7.5 | 7.0 – j6.3 | 33.6 | 44.9 | 56.5 | -7 | |
| BLM7G | 1822S-80ABG | | | | 1 | | | | | I | |
| 1805 | 8.0 - j13.4 | 31.8 | 45.8 | 50.3 | -1.7 | 14.8 – j8.7 | 33 | 44.6 | 58.1 | -5.5 | |
| 1842.5 | 8.0 – j13.4 | 31.9 | 45.8 | 49.2 | -1 | 16.3 – j4.3 | 33.3 | 44.7 | 57.5 | -7.4 | |
| 1880 | 8.0 – j13.4 | 32.1 | 45.8 | 50 | -0.3 | 12.7 – j7.1 | 33.2 | 44.5 | 57.3 | -4.3 | |
| 1930 | 8.0 – j13.4 | 32.1 | 45.8 | 50.3 | -0.6 | 12.8 – j7.3 | 33.2 | 44.4 | 56.3 | -3.4 | |
| 1960 | 8.0 – j13.4 | 32.4 | 45.7 | 49.9 | -0.4 | 11.1 – j6.8 | 33.5 | 44.5 | 56.1 | -3.6 | |
| 1990 | 7.7 – j15.2 | 32.2 | 45.7 | 47 | -0.7 | 9.0 – j7.7 | 33.4 | 44.8 | 55.9 | -3.4 | |
| 2110 | 8.1 – j13.4 | 33 | 45.8 | 52.1 | -6.1 | 7.6 – j8.0 | 33.6 | 44.7 | 56.1 | -6.7 | |
| 2140 | 6.5 – j12.8 | 32.7 | 45.7 | 50.8 | -8.9 | 7.6 – j8.0 | 33.5 | 44.5 | 55.7 | -7.7 | |
| 2170 | 7.0 – j14.1 | 32.4 | 45.6 | 49.1 | -10 | 8.6 – j9.0 | 33.3 | 44.8 | 55.8 | -7.8 | |
| Peaking | section | | | | 1 | | | | | I | |
| BLM7G | 1822S-80AB | | | | | | | | | | |
| 1810 | 2.6 – j5.9 | 29.2 | 48.6 | 49.6 | -2.7 | 5.4 – j5.1 | 30.3 | 47.4 | 56.4 | -5.6 | |
| 1840 | 2.7 – j5.8 | 29.9 | 48.5 | 49.3 | -3.8 | 4.9 – j4.8 | 30.9 | 47.5 | 56.3 | -6.2 | |
| 1880 | 2.6 – j5.8 | 29.6 | 48.5 | 48.5 | -2.4 | 4.8 – j4.3 | 30.6 | 47.4 | 55.3 | -5 | |
| 1930 | 2.6 – j5.8 | 29.9 | 48.4 | 47.9 | -1.1 | 4.3 – j4.2 | 30.8 | 47.4 | 54.3 | -2.9 | |
| 1960 | 2.6 – j5.8 | 29.9 | 48.4 | 48 | -1 | 4.2 – j4.2 | 30.8 | 47.5 | 54.3 | -2.2 | |
| 1990 | 2.6 – j5.7 | 29.6 | 48.3 | 47.5 | -2.1 | 3.6 – j4.0 | 30.4 | 47.4 | 53.8 | -3.9 | |
| 2110 | 2.6 – j5.8 | 29.8 | 48.3 | 48.3 | -3.6 | 3.1 – j4.1 | 30.2 | 47.4 | 52.6 | -4.7 | |
| 2140 | 2.6 – j5.8 | 29.8 | 48.3 | 48.6 | -4.1 | 3.1 – j4.7 | 30.3 | 47.6 | 51.9 | -3.9 | |
| 2170 | 2.6 – j5.8 | 29.5 | 48.2 | 46 | -5.4 | 2.6 – j4.7 | 30.1 | 47.5 | 51.2 | -6.4 | |

Table 9. Typical impedance ...continued

Measured load-pull data at 3 dB gain compression point; test signal: pulsed CW; $T_{case} = 25 \ C$; $V_{DS} = 28 \ V$; $t_p = 100 \ \mu s$; $\delta = 10 \ \%$; $Z_S = 50 \ \Omega$; $I_{Dq1} = 40 \ mA$ (carrier section, driver stage); $I_{Dq2} = 110 \ mA$ (carrier section, final stage); $I_{Dq1} = 80 \ mA$ (peaking section, driver stage); $I_{Dq2} = 200 \ mA$ (peaking section, final stage). Typical values unless otherwise specified.

| | tuned for m | naximum o | utput p | ower | | tuned for m | aximum p | ower a | dded effic | iency |
|-------|-------------|---------------------|---------|------------------|---------------------|-------------|---------------------|--------|------------------|---------------------|
| f | ZL | G _{p(max)} | PL | ໗ _{add} | AM-PM conversion | ZL | G _{p(max)} | PL | ໗ _{add} | AM-PM conversion |
| (MHz) | (Ω) | (dB) | (W) | (%) | (deg) | (Ω) | (dB) | (W) | (%) | (deg) |
| BLM7G | 1822S-80ABG | | 1 | I | I. | | | 1 | | I |
| 1810 | 3.0 – j8.9 | 29.3 | 48.4 | 50.6 | -1.7 | 5.3 – j7.6 | 30.3 | 47.5 | 57.5 | -5.3 |
| 1840 | 2.7 – j8.7 | 29.1 | 48.3 | 48.4 | -4.4 | 5.0 – j7.5 | 30.2 | 47.5 | 56.9 | -7.5 |
| 1880 | 3.0 – j8.8 | 29.4 | 48.4 | 50.5 | -2.3 | 4.7 – j7.1 | 30.3 | 47.4 | 56.4 | -5.1 |
| 1930 | 2.7 – j9.0 | 29.6 | 48.4 | 48.7 | -2.7 | 4.4 – j7.0 | 30.6 | 47.4 | 56.1 | -5.5 |
| 1960 | 2.7 – j9.0 | 29.6 | 48.4 | 48.7 | -2.7 | 4.0 – j6.8 | 30.6 | 47.4 | 55.9 | -5.3 |
| 1990 | 2.7 – j8.9 | 29.7 | 48.4 | 48 | -2 | 3.8 – j7.1 | 30.6 | 47.5 | 55 | -3.7 |
| 2110 | 2.7 – j9.5 | 29.9 | 48.5 | 49.5 | -3.4 | 2.8 – j7.6 | 30.6 | 47.6 | 54.9 | -4.2 |
| 2140 | 2.6 – j9.5 | 29.9 | 48.3 | 49.1 | -4 | 2.6 – j7.9 | 30.5 | 47.6 | 53.7 | -3.2 |
| 2170 | 2.4 – j9.7 | 29.7 | 48.3 | 47.4 | -5.5 | 2.6 – j8.2 | 30.5 | 47.7 | 53 | -4.6 |

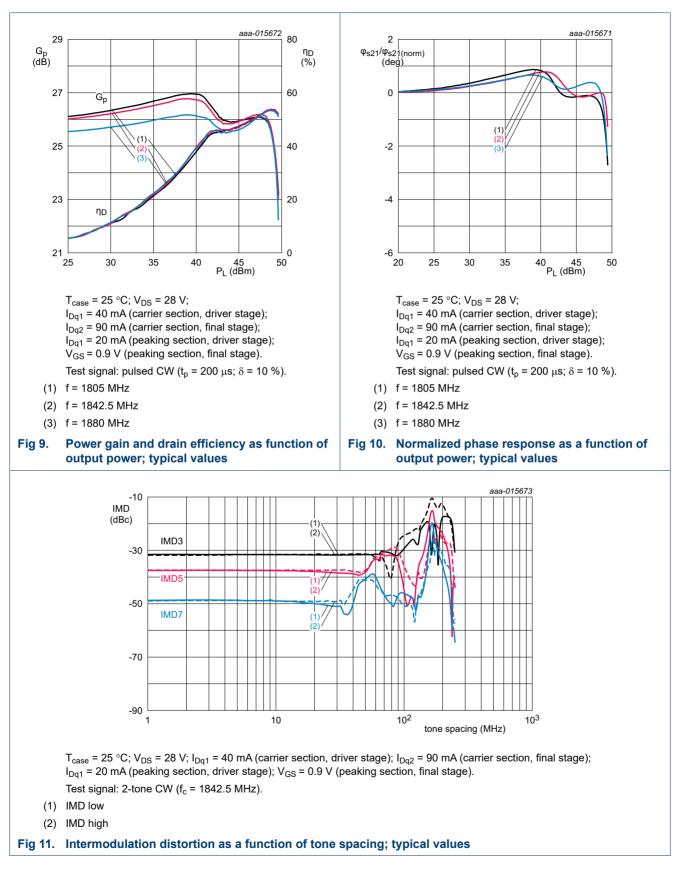
8.4 Graphs



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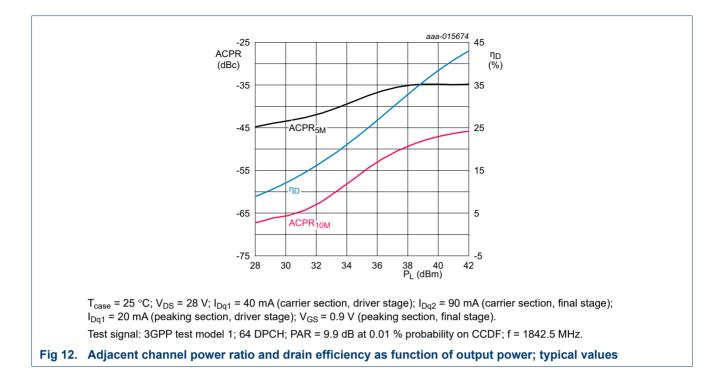
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BLM7G1822S-80AB_S-80ABG#3

Product data sheet

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9. Package outline

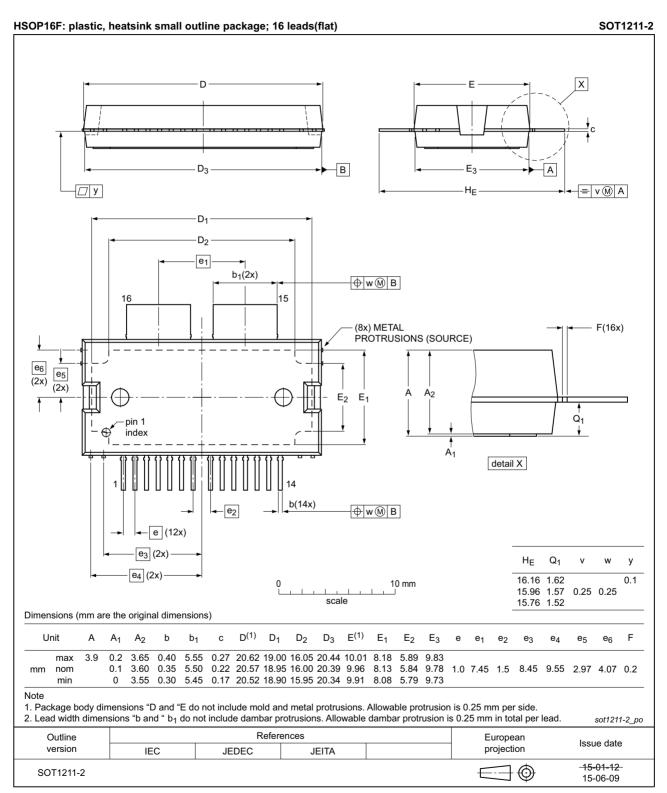
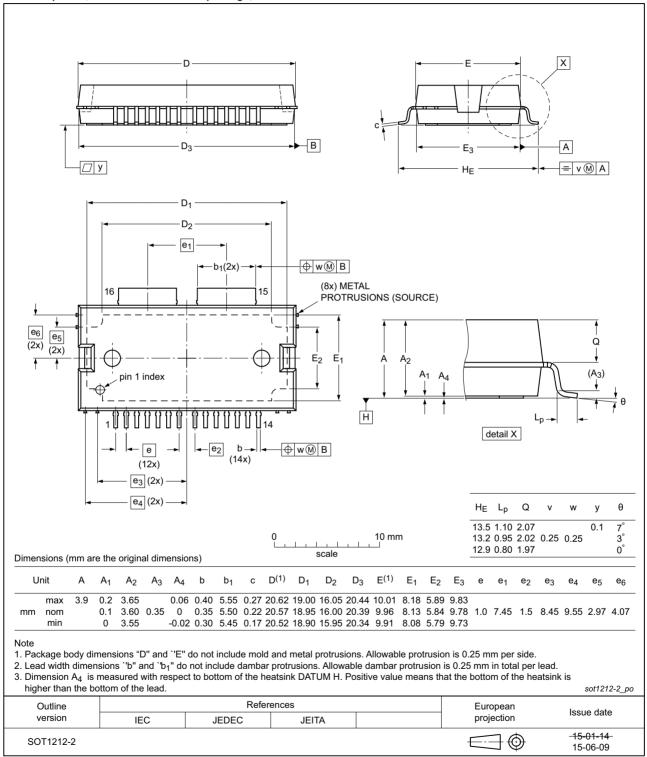


Fig 13. Package outline SOT1211-2 (HSOP16F)

LDMOS 2-stage power MMIC

SOT1212-2



HSOP16: plastic, heatsink small outline package; 16 leads

Fig 14. Package outline SOT1212-2 (HSOP16)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

| Table 10. Abbreviations | | | | | | | | |
|-------------------------|--|--|--|--|--|--|--|--|
| Acronym | Description | | | | | | | |
| AM | Amplitude Modulation | | | | | | | |
| 3GPP | 3rd Generation Partnership Project | | | | | | | |
| CCDF | Complementary Cumulative Distribution Function | | | | | | | |
| CW | Continuous Wave | | | | | | | |
| DPCH | Dedicated Physical CHannel | | | | | | | |
| ESD | ElectroStatic Discharge | | | | | | | |
| GEN7 | Seventh Generation | | | | | | | |
| LDMOS | Laterally Diffused Metal Oxide Semiconductor | | | | | | | |
| MMIC | Monolithic Microwave Integrated Circuit | | | | | | | |
| MTF | Median Time to Failure | | | | | | | |
| PAR | Peak-to-Average Ratio | | | | | | | |
| PM | Phase Modulation | | | | | | | |
| VSWR | Voltage Standing-Wave Ratio | | | | | | | |
| W-CDMA | Wideband Code Division Multiple Access | | | | | | | |

12. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | | | |
|-----------------------------|--|---------------------------------|------------------|---------------------------------|--|--|--|--|--|
| BLM7G1822S-80AB_S-80ABG#3 | 20150901 | BLM7G1822S-80AB_S -80ABG v.2 | | | | | | | |
| Modifications: | • The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. | | | | | | | | |
| | Legal texts | have been adapted to the | e new company na | me where appropriate. | | | | | |
| BLM7G1822S-80AB_S-80ABG v.2 | 20150701 | Product data sheet | - | BLM7G1822S-80AB_ S-80ABG v.1 | | | | | |
| BLM7G1822S-80AB_S-80ABG v.1 | 20141128 | Product data sheet | - | - | | | | | |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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